Unitized Semiconductor Devices - Page 1 of 1



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# Inclosure Material:

Metal

# Overall Length:

Between 0.690 inches and 0.770 inches

## **Terminal Length:**

Between 0.150 inches and 0.230 inches

#### **Overall Height:**

Between 0.080 inches and 0.120 inches

#### **Overall Width:**

Between 0.280 inches and 0.310 inches

# Component Name And Quantity:

4 transistor

**Mounting Method:** 

Terminal

Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon all transistor

## Voltage Rating In Volts Per Characteristic:

100.0 drain to source voltage all transistor and 100.0 drain to gate voltage all transistor and 20.0 gate to source voltage all transistor

#### **Current Rating Per Characteristic:**

4.00 amperes off-state current, peak all transistor and 1.00 amperes drain current all transistor

## Power Rating Per Characteristic:

2.5 watts total device dissipation all transistor

#### Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

#### **Terminal Type And Quantity:**

14 pin

Shelf Life:

N/a

#### Unit Of Measure:

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# Demilitarization:

No

## Fiig:

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